

# PJQ44605AP-AU

## 60V P-Channel Enhancement Mode MOSFET

**Voltage**

**-60 V**

**Current**

**-38 A**

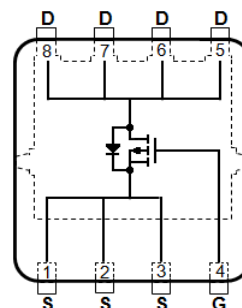
### Features

- $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-20A < 28m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-10A < 38m\Omega$
- 100% UIS tested
- Reliable and Rugged
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

### Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

DFN3333-8L



### Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	-60	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>(Note 3)</sup>	$T_C=25^\circ\text{C}$	$I_D$	-38	A
	$T_C=100^\circ\text{C}$		-27	
Pulsed Drain Current <sup>(Note 1)</sup>	$T_C=25^\circ\text{C}$	$I_{DM}$	-80	
Power Dissipation	$T_C=25^\circ\text{C}$	$P_D$	75	W
	$T_C=100^\circ\text{C}$		38	
Continuous Drain Current <sup>(Note 4)</sup>	$T_A=25^\circ\text{C}$	$I_D$	-6.7	A
	$T_A=70^\circ\text{C}$		-6	
Power Dissipation	$T_A=25^\circ\text{C}$	$P_D$	2.5	W
	$T_A=70^\circ\text{C}$		1.8	
Single Pulse Avalanche Current <sup>(Note 5)</sup>		$I_{AS}$	-14	A
Single Pulse Avalanche Energy <sup>(Note 5)</sup>		$E_{AS}$	98	mJ
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~175	$^\circ\text{C}$
Thermal Resistance <sup>(Note 4)</sup>	Junction to Case	$R_{\theta JC}$	2	$^\circ\text{C/W}$
	Junction to Ambient	$R_{\theta JA}$	60	

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## Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

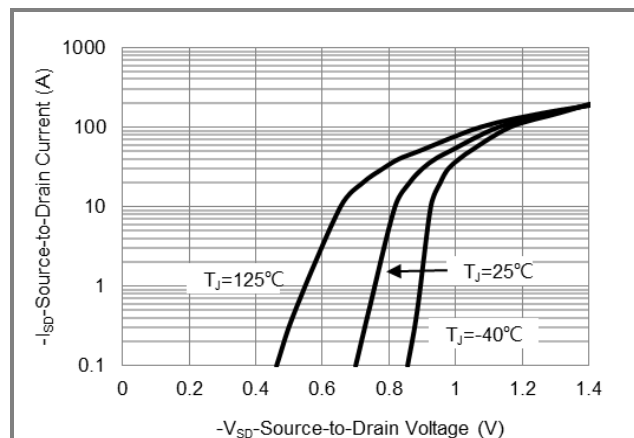
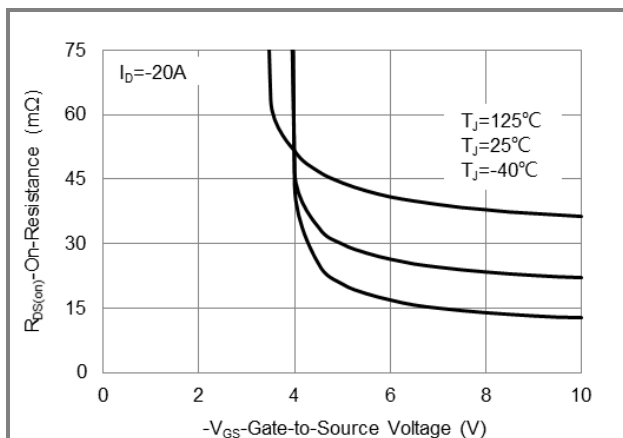
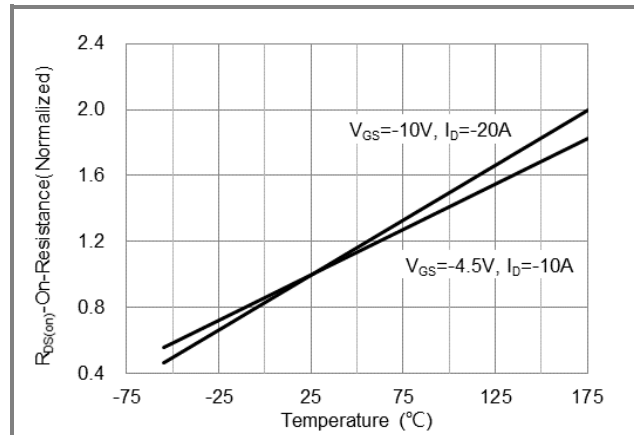
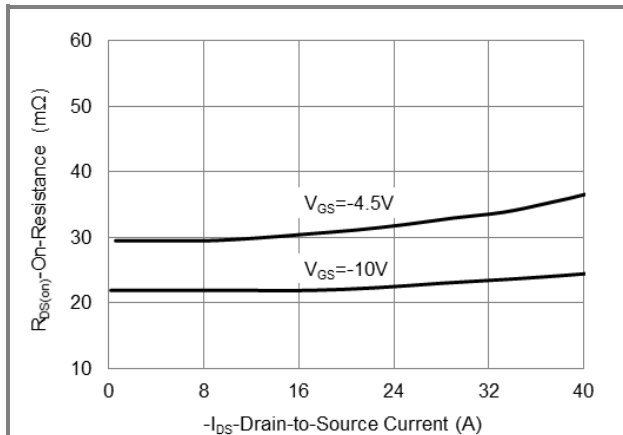
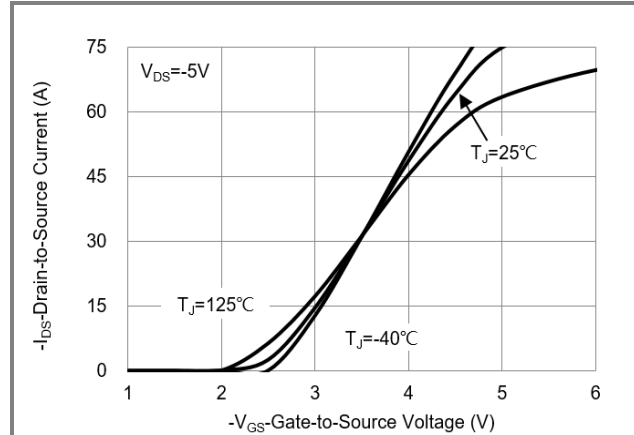
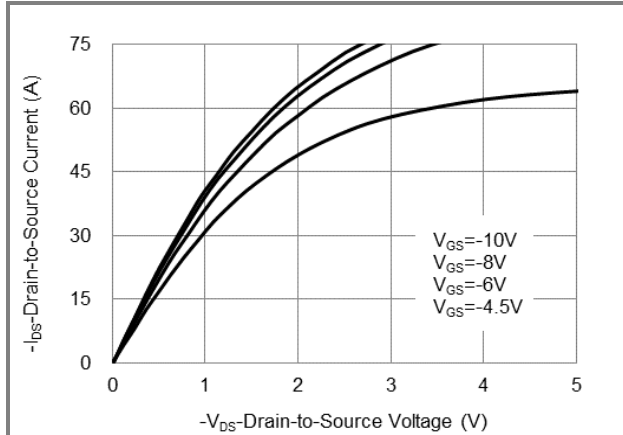
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-60	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-1.7	-2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-20A	-	22.3	28	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-10A	-	29.5	38	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-60V, V <sub>GS</sub> =0V	-	-	-1	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
Dynamic <sup>(Note 6)</sup>						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-30V, I <sub>D</sub> =-20A, V <sub>GS</sub> =-10V	-	44	58	nC
Gate-Source Charge	Q <sub>gs</sub>		-	11	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	7	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1MHz	-	2530	3290	pF
Output Capacitance	C <sub>oss</sub>		-	151	228	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	108	162	
Gate resistance	R <sub>g</sub>	f=1MHz	-	4.8	-	Ω
Turn-On Delay Time	t <sub>d(on)</sub>	V <sub>DS</sub> =-30V, I <sub>D</sub> =-20A, V <sub>GS</sub> =-10V, R <sub>G</sub> =3Ω (Note 2)	-	7	-	ns
Turn-On Rise Time	t <sub>r</sub>		-	9	-	
Turn-Off Delay Time	t <sub>d(off)</sub>		-	41	-	
Turn-Off Fall Time	t <sub>f</sub>		-	21	-	
Drain-Source Diode						
Diode Forward Current	I <sub>S</sub>	T <sub>C</sub> =25°C	-	-	-38	A
Pulsed Diode Forward Current	I <sub>SM</sub>		-	-	-80	
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-20A, V <sub>GS</sub> =0V	-	-0.85	-1.3	V
Reverse Recovery Time	T <sub>rr</sub>	V <sub>DD</sub> =-30V,V <sub>GS</sub> =0V	-	16	-	ns
Reverse Recovery Charge	Q <sub>rr</sub>	I <sub>S</sub> =-20A,dI <sub>S</sub> /dt=100A/us	-	10	-	nC

### NOTES :

1. Pulse width≤300us, Duty cycle≤2%.
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
5. E<sub>AS</sub> is calculated based on the condition of L=1mH, I<sub>AS</sub>=-14A, V<sub>DD</sub>=-30V, V<sub>GS</sub>=-10V. 100% test at L=0.5mH, I<sub>AS</sub>=-14A in production.
6. Guaranteed by design, not subject to production testing.

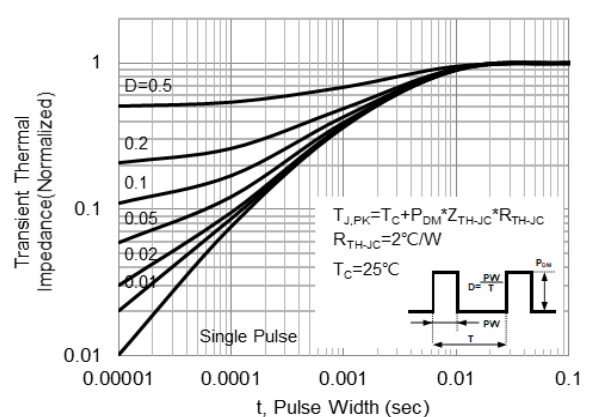
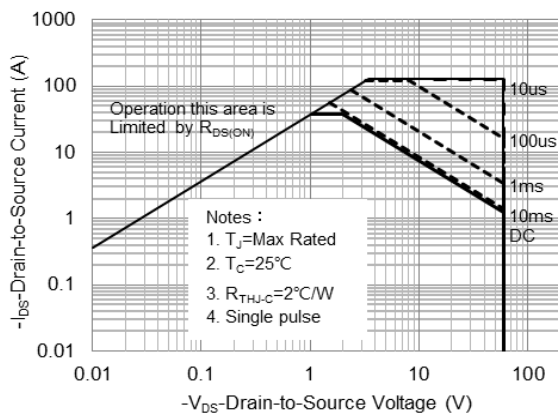
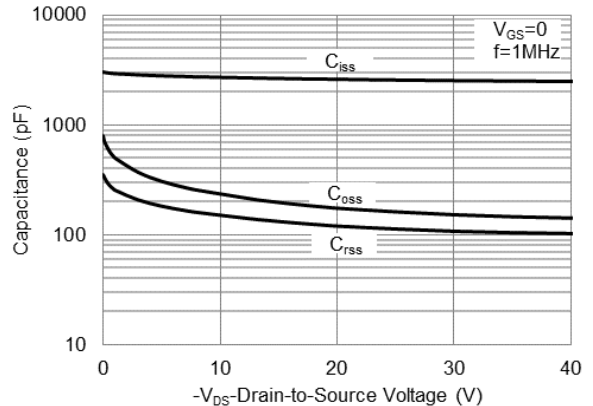
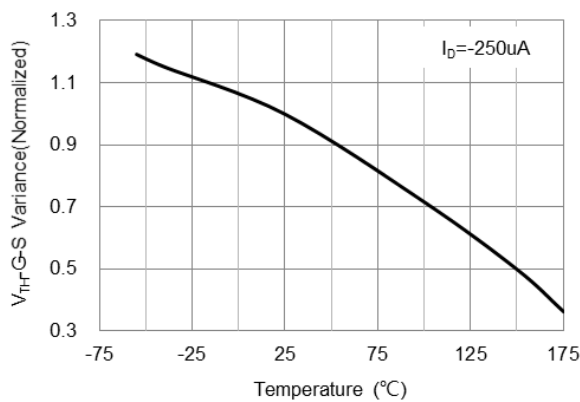
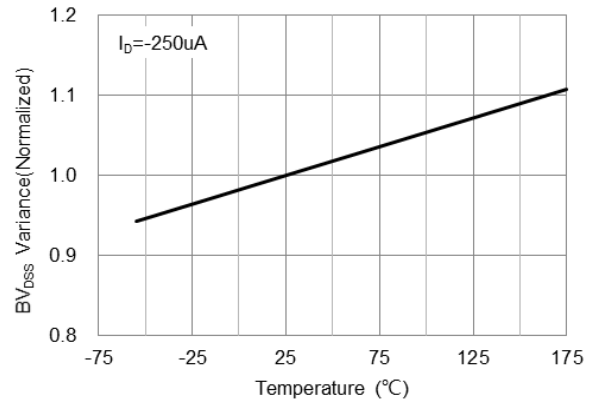
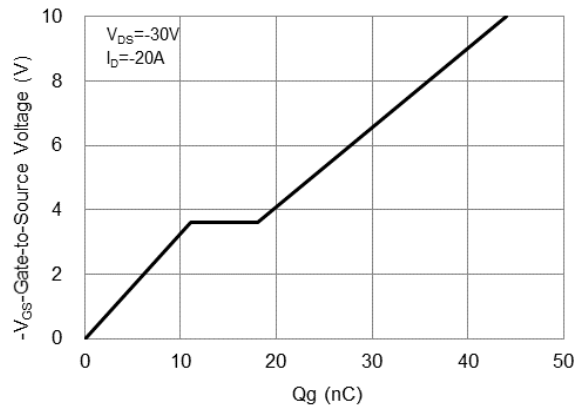
# PJQ44605AP-AU

## TYPICAL CHARACTERISTIC CURVES



# PJQ44605AP-AU

## TYPICAL CHARACTERISTIC CURVES

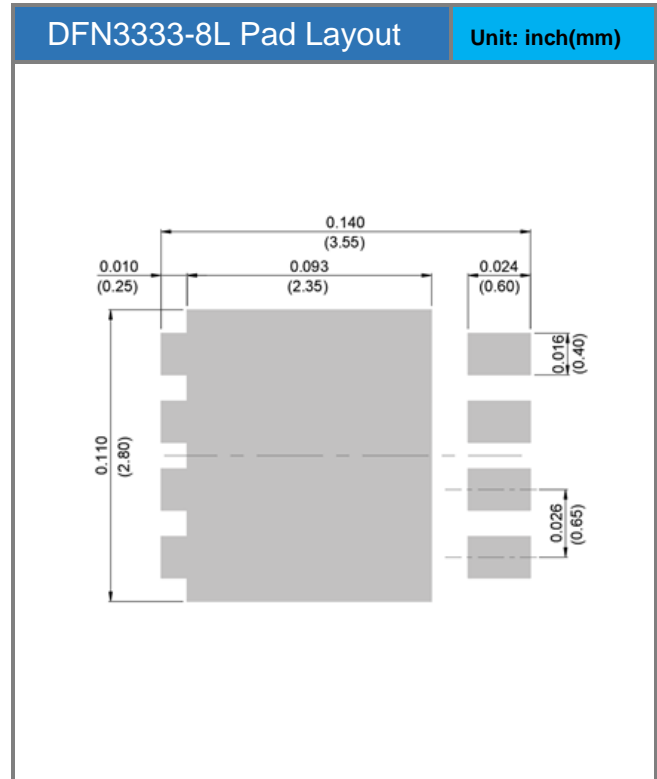
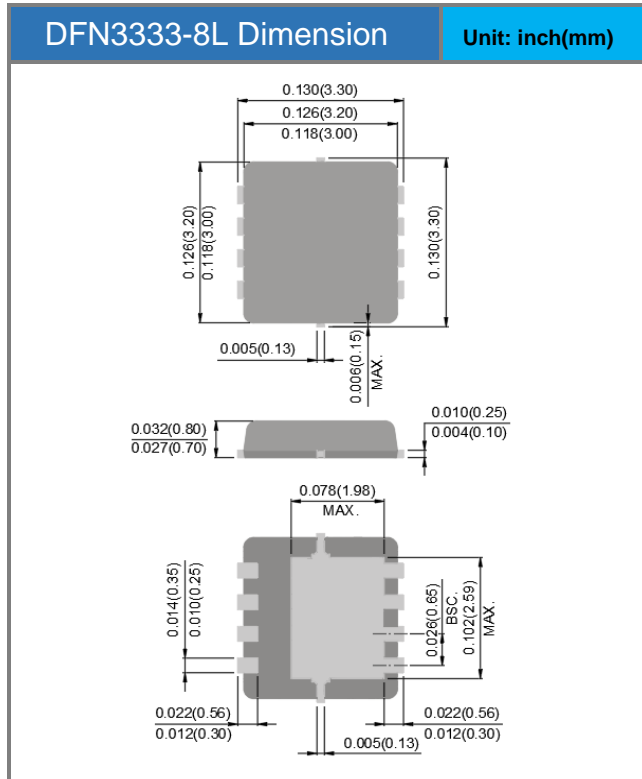


# PJQ44605AP-AU

## Product and Packing Information

Part No.	Package Type	Packing Type	Marking
PJQ44605AP-AU	DFN3333-8L	5K pcs / 13" reel	44605A

## Packaging Information & Mounting Pad Layout



## PJQ44605AP-AU

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